SUPPORTING INFORMATION FOR:

Study on a polymerizable visible light initiator for fabrication of biosafety materials

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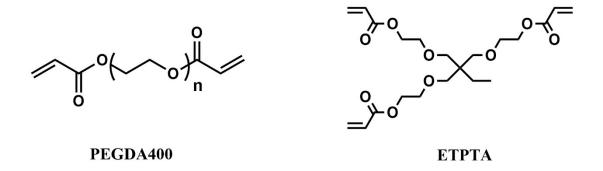
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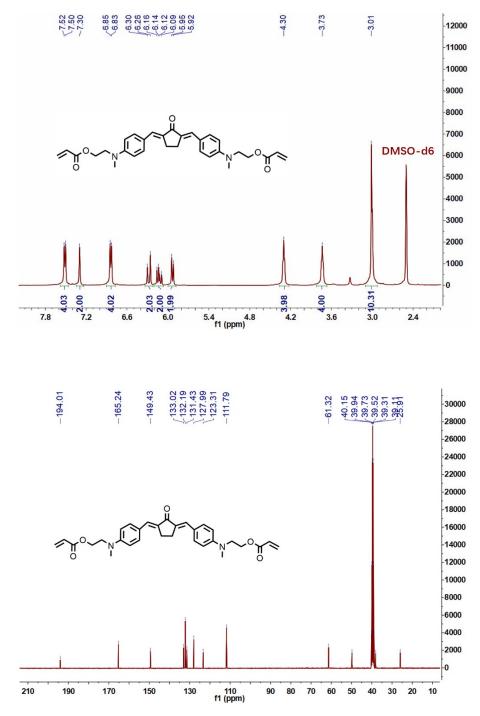


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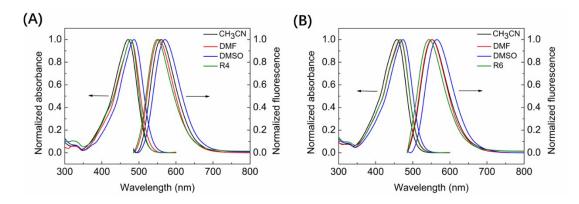


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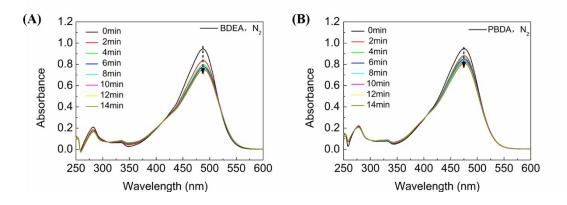


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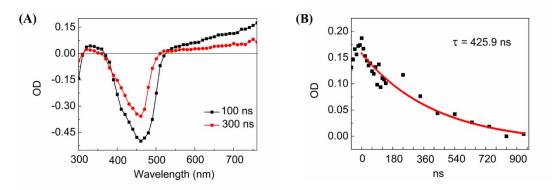


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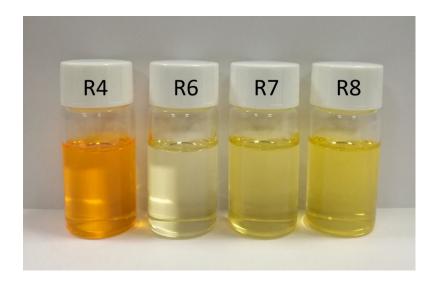


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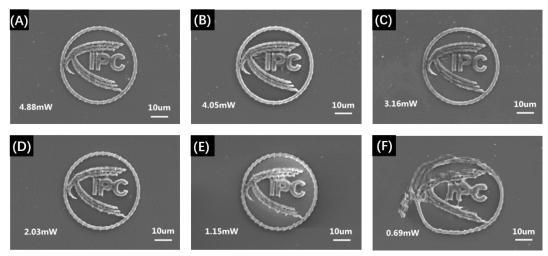


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